NSN 5961-01-102-2866

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-102-2866 **Inclosure Material:** Plastic **Overall Length:** 0.620 inches **Overall Height:** 0.190 inches **Overall Width:** 0.405 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open and 60.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 8.00 amperes source cutoff current and 120.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 2.2 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 tab, solder lug **Specification Data:** 80131-release6304 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**